

*Ionic Conductivity and Coulometric Titration of Copper Selenide.* T. TAKAHASHI, O. YAMAMOTO, F. MATSUYAMA, AND Y. NODA. Department of Applied Chemistry, Nagoya University, Nagoya 464, Japan. The ionic conductivity of copper selenide was measured in the temperature range of 30–180°C by blocking the electronic current by the copper ion high conductivity solid electrolyte,  $37\text{CuBr} \cdot 3[\text{C}_6\text{H}_{12}\text{N}_2 \cdot 2\text{CH}_3\text{Br}]$ . It was found that the  $\alpha$ -phase of  $\text{Cu}_{2-\delta}\text{Se}$  has a high ionic conductivity; for example,  $\text{Cu}_{1.75}\text{Se}$  exhibited an ionic conductivity of  $3 \times 10^{-2} \text{ ohm}^{-1} \text{ cm}^{-1}$  at room temperature. The coulometric titration of copper selenide was carried out with the help of the cell,  $\text{Au}/\text{Cu}_{2-\delta}\text{Se}/\text{solid electrolyte}/\text{Cu}$ ; from the temperature dependence of the cell voltage, the  $\beta$ - $\alpha$  transition temperatures of  $\text{Cu}_{2-\delta}\text{Se}$  were determined as functions of  $\delta$ .

*A Study of the MgO-V<sub>2</sub>O<sub>5</sub> System.* G. M. CLARK AND R. MORLEY. Department of Applied Chemical and Biological Sciences, The Polytechnic, Huddersfield HD1 3DH, England. An investigation was made of solid-solid reactions in  $\text{MgO}/\text{V}_2\text{O}_5$  mixtures of various stoichiometries. Three compounds were obtained:  $\text{Mg}_3\text{V}_2\text{O}_8$ ,  $\text{Mg}_2\text{V}_2\text{O}_7$ , and  $\text{MgV}_2\text{O}_6$ . No evidence was obtained to indicate formation of other  $\text{MgO}-\text{V}_2\text{O}_5$  compounds reported in the literature. DTA data are listed for the three compounds and some observations are made on the mechanism of formation of the compounds. A new polymorph of  $\text{Mg}_2\text{V}_2\text{O}_7$  was prepared and its space group and cell parameters were deduced from the X ray powder diffraction pattern. This polymorph undergoes a transition, reversible with difficulty, at 980–990°K.

*Etude par Diffractions X et Neutronique d'un Monocristal de UCr<sub>2</sub>O<sub>6</sub> Obtenu par Synthèse Hydrothermale sous Très Haute Pression. Détermination des Structures Cristallographique et Magnétique.* A. COLLOMB, M. GONDRAND, M. S. LEHMANN, J. J. CAPPONI, AND J. C. JOUBERT. Laboratoire des Rayon X, C.N.R.S., B.P. 166, Centre de Tri, 38042 Grenoble Cedex, France. The structure of  $\text{UCr}_2\text{O}_6$ ,  $\text{PbSb}_2\text{O}_6$  type compound, has been refined from X ray and neutron single crystal data. The symmetry is trigonal, space group  $\text{P}\bar{3}1\text{m}$ , with  $a = 4.990$  (1) Å and  $c = 4.622$  (1) Å. There is one molecule per unit cell. The uranium, chromium and oxygen atoms occupy the  $1a$  (0, 0, 0),  $2d(\frac{1}{3}, \frac{2}{3}, \frac{1}{2})$ ,  $6k(x, 0, z)$  positions respectively with  $x = 0.3405$  (3) and  $z = 0.2647$  (2). The final  $R$  factors are 0.033 for the X ray data and 0.0294 for the neutron data. The anisotropic temperature factors have been introduced in the last stage of both refinements. The average cation-anion interatomic distances are  $\text{U}-\text{O} = 2.094$  (1) Å,  $\text{Cr}-\text{O} = 1.9726$  (8) Å. From these values it can be deduced that the uranium and chromium are hexavalent and trivalent, respectively. From powder diffraction diagrams at 298 and 4.2°K, it has been determined that the spins of the  $\text{Cr}^{3+}$  are located in the basal plane with an antiferromagnetic type arrangement. The value of the magnetic moment is 2.6  $\mu\text{B}$ .

*The Electrical Conductivity and Thermodynamic Behavior of SrO-Doped Nonstoichiometric Cerium Dioxide.* R. N. BLUMENTHAL AND J. E. GARNIER. Metallurgy and Materials Science, College of Engineering, Marquette University, Milwaukee, Wisconsin 53233. Electrical conductivity and thermogravimetric measurements were made on SrO-doped nonstoichiometric cerium dioxide (i.e.,  $\text{Ce}_{1-y}\text{Sr}_y\text{O}_{2-y-x}$ ) as a function of temperature ( $\sim 700^\circ$  to  $1500^\circ\text{C}$ ) and oxygen partial pressure ( $\sim 1$  to  $10^{-21}$  atm). Assuming limiting case defect models the ionic  $\sigma_i$ , and electronic,  $\sigma_e$  conductivities were calculated from this data. In the region where  $y \gg x$  (i.e. at low temperatures and high oxygen pressures) the conductivity is independent of  $\text{P}_{\text{O}_2}$  and up to approximately 3 mole % SrO it is proportional to mole % SrO. The equation for ionic conductivity,  $\sigma_i \approx [4.5 \pm 0.5][m/o\text{SrO}]\exp(-0.58/kT)$ , was obtained by fitting the conductivity data in this region to an expression derived on the basis of an oxygen vacancy model. In the composition region between approximately  $x = 10^{-3}$  and  $x = 10^{-2}$ , both the thermodynamic behavior and the electrical conductivity were shown to be consistent with a defect model involving randomly distributed doubly ionized oxygen vacancies and electrons localized on normal cerium sites. In this region, the electronic conductivity varies linearly with  $x$  and the electronic mobility decreases with increasing SrO content.